

Single 2-Input NOR Gate

General Description

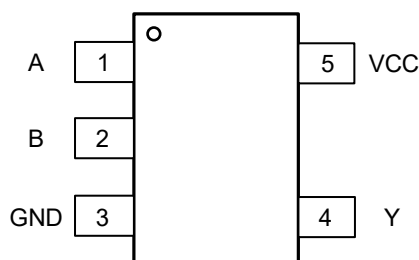
The ETQ74LV1T02 is a high performance single 2-input NOR Gate operating from a 1.6V to 5.5V supply. This device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive.

Features

- Designed for 1.6V to 5.5V V_{CC} Operation
- Over-Voltage Tolerant Inputs Accept Voltages to 5.5V
- $\pm 8\text{mA}$ Balanced Sink and Source Output Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- These Devices are Pb-Free and RoHS Compliant
- Multiple Package Options Automotive AEC-Q100 Grade 1 Qualified
 - Ambient Temperature Range of -40°C to 125°C
 - ESD HBM $\pm 4\text{KV}$ PASS
 - ESD CDM $\pm 1\text{KV}$ PASS
 - Latch Up Current to $\pm 100\text{mA}$ PASS
- Part No. and Package Information

Part No.	Package	Packing Option	MSL
ETQ74LV1T02	SC70-5 (1.3mm $\times$ 2.1mm)	Tape and Reel, 3K/Reel	1

Pin Configuration



SC70-5

Figure1. Pin Configuration

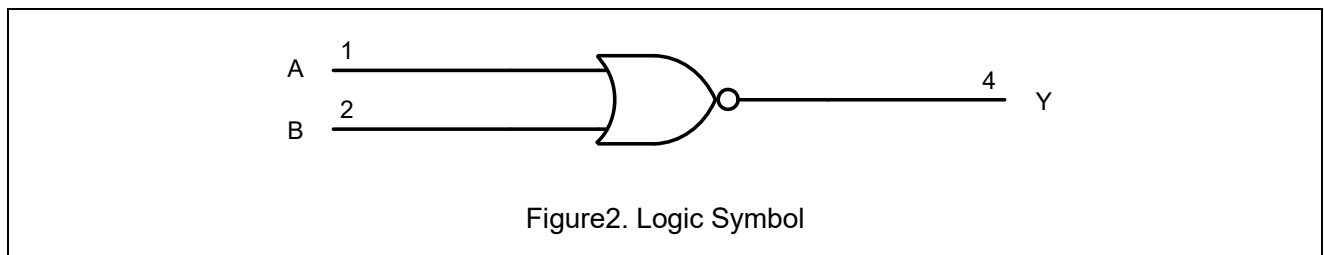
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Pin Function

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Pin No.	Pin Name	Function
1	A	Input A
2	B	Input B
3	GND	Ground
4	Y	Output Y
5	VCC	Supply Voltage

Block Diagram



Function Table

Input		Output
A	B	Y
L	L	H
L	H	L
H	L	L
H	H	L

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Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage (VCC Pin)		-0.5 to 7.0	V
V _I	DC Input Voltage ⁽¹⁾		-0.5 ≤ V _I ≤ 7.0	V
V _O	DC Output Voltage Output in Higher or Low State		-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current V _I < GND		-50	mA
I _{OK}	DC Output Diode Current, V _O < GND, V _O > V _{CC}		±50	mA
I _O	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current Per Supply Pin		+100	mA
I _{GND}	DC Ground Current Per Supply Pin		-100	mA
T _{STG}	Storage Temperature Range		-65 to 150	°C
T _L	Lead Temperature, Soldering 10 Seconds		260	°C
T _J	Max Junction Temperature		150	°C
V _{ESD}	ESD Classification	Human Body Model ⁽²⁾	±4000	V
		Charged Device Model ⁽³⁾	±1000	
I _{LU}	Latch Up Current Above V _{CC} and GND at 125°C ⁽⁴⁾		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Note1: I_O absolute maximum rating must be observed.

Note2: HBM tested per AEC-Q100-002(JEDEC JS-001);

Note3: CDM tested per AEC-Q100-011(JEDEC JS-002);

Note4: Latch up Current Maximum Rating tested per AEC-Q100-004(JEDEC JESD78F).

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
R _{θJA}	SC70-5	Thermal Characteristics, Thermal Resistance, Junction-to-Air	300	°C/W
P _D	SC70-5	Power Dissipation in Still Air at 85°C	215	mW

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage Operating		1.6	5.5	V
V _I	DC Input Voltage		0	V _{CC}	V
V _O	DC Output Voltage (High or Low State)		0	V _{CC}	V
T _A	Operating Temperature Range		-40	125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 1.8V to 5.5V	0	20	ns/V

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Electrical Characteristics

DC Electrical Characteristics

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-level Input Voltage		1.65~1.8	0.94			1.0		V
			2.0	0.99			1.03		
			2.25~2.5	1.135			1.18		
			2.75	1.21			1.23		
			3.0~3.3	1.35			1.37		
			3.6	1.47			1.48		
			4.5~5.0	2.02			2.03		
			5.5	2.10			2.11		
V _{IL}	Low-level Input Voltage		1.65~2.0			0.45		0.40	V
			2.25~2.75			0.75		0.71	
			3.0~3.6			0.80		0.65	
			4.5~5.5			0.80		0.80	
V _{OH}	High-level Output Voltage	I _{OH} = -20μA	1.65~5.5	V _{CC} - 0.1	V _{CC}		V _{CC} - 0.1		V
		I _{OH} = -2mA	1.65	1.28			1.21		
		I _{OH} = -2mA	1.8	1.5			1.45		
		I _{OH} = -2.3mA	2.3	2.0			2.0		
		I _{OH} = -3mA	2.3	2.0			1.93		
		I _{OH} = -3mA	2.5	2.25			2.15		
		I _{OH} = -3mA	3.0	2.78			2.7		
		I _{OH} = -5.5mA	3.0	2.6			2.49		
		I _{OH} = -5.5mA	3.3	2.9			2.8		
		I _{OH} = -4mA	4.5	4.2			4.1		
		I _{OH} = -8mA	4.5	4.1			3.95		
		I _{OH} = -8mA	5.5	4.6			4.5		
V _{OL}	Low-level Output Voltage	I _{OL} = 20μA	1.65~5.5			0.1		0.1	V
		I _{OL} = 2mA	1.65			0.2		0.25	
		I _{OL} = 2.3mA	2.3			0.1		0.15	
		I _{OL} = 3mA	2.3			0.15		0.2	
		I _{OL} = 3mA	3.0			0.1		0.15	
		I _{OL} = 5.5mA	3.0			0.2		0.252	
		I _{OL} = 4mA	4.5			0.15		0.2	
		I _{OL} = 8mA	4.5			0.3		0.35	
I _I	Input Leakage Current	V _I = 5.5V or GND	0~5.5			±0.1		±1.0	μA

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DC Electrical Characteristics (Continued)

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
I _{CC}	Quiescent Supply Current	V _I = 5.5 V or GND	5.5			1.0		10	μA
ΔI _{CC}	Additional Supply Current	Per Input Pin; V _I = 0.3V or 1.1V; I _O = 0mA; Other Pins at V _{CC} or GND	1.8			10		10	μA
		Per Input Pin; V _I = 0.3V or 3.4V; I _O = 0mA; Other Pins at V _{CC} or GND	5.5			1.35		1.5	mA

AC Electrical Characteristics

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation Delay (Figure3 & 4)	C _L = 15pF	1.8		12.2	15.4		17.4	ns
		C _L = 30pF	1.8		13.1	16.6		17.6	
		C _L = 15pF	2.5		8.4	10.4		12	
		C _L = 30pF	2.5		9.1	11.3		13	
		C _L = 15pF	3.3		6.7	8.3		9.4	
		C _L = 30pF	3.3		7.3	8.9		10.2	
		C _L = 15pF	5.0		5.6	6.5		7.3	
		C _L = 30pF	5.0		6	7		7.9	

Capacitance Characteristics

Symbol	Parameter	Condition	Typ	Unit
C _{IN}	Input Capacitance	V _{CC} = 5.5V, V _I = 0V or V _{CC}	5	pF
C _{PD}	Power Dissipation Capacitance ⁽⁵⁾	10MHz, V _{CC} = 3.3V, V _I = 0V or V _{CC}	26	pF
		10MHz, V _{CC} = 5.5V, V _I = 0V or V _{CC}	30	

Note5: C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

Σ(C_L × V_{CC}² × f_o) = sum of outputs.

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AC Test Circuit

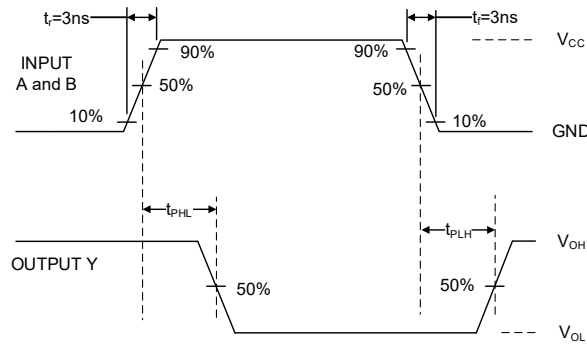
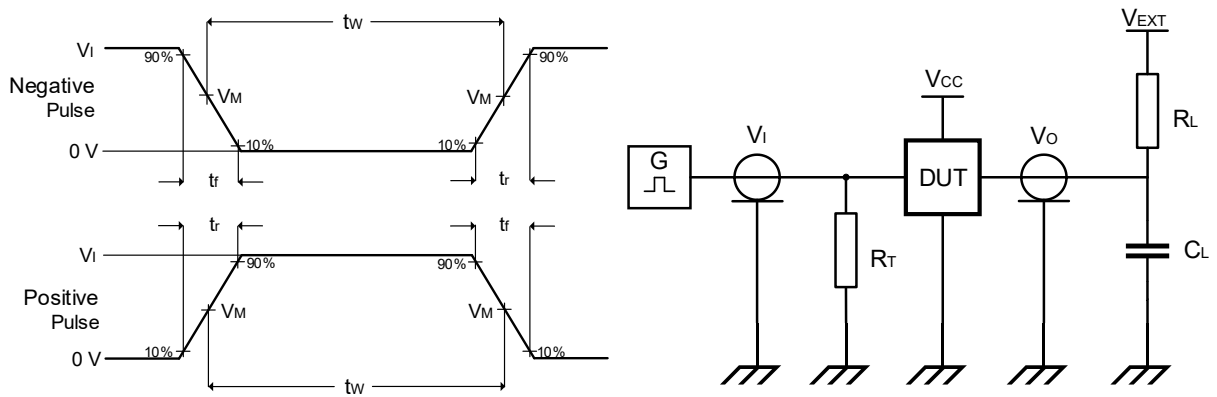


Figure3. Switching Waveform



Measurement points are given in [Table 1](#).

Definitions test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Figure4. Test Circuit for Measuring Switching Times

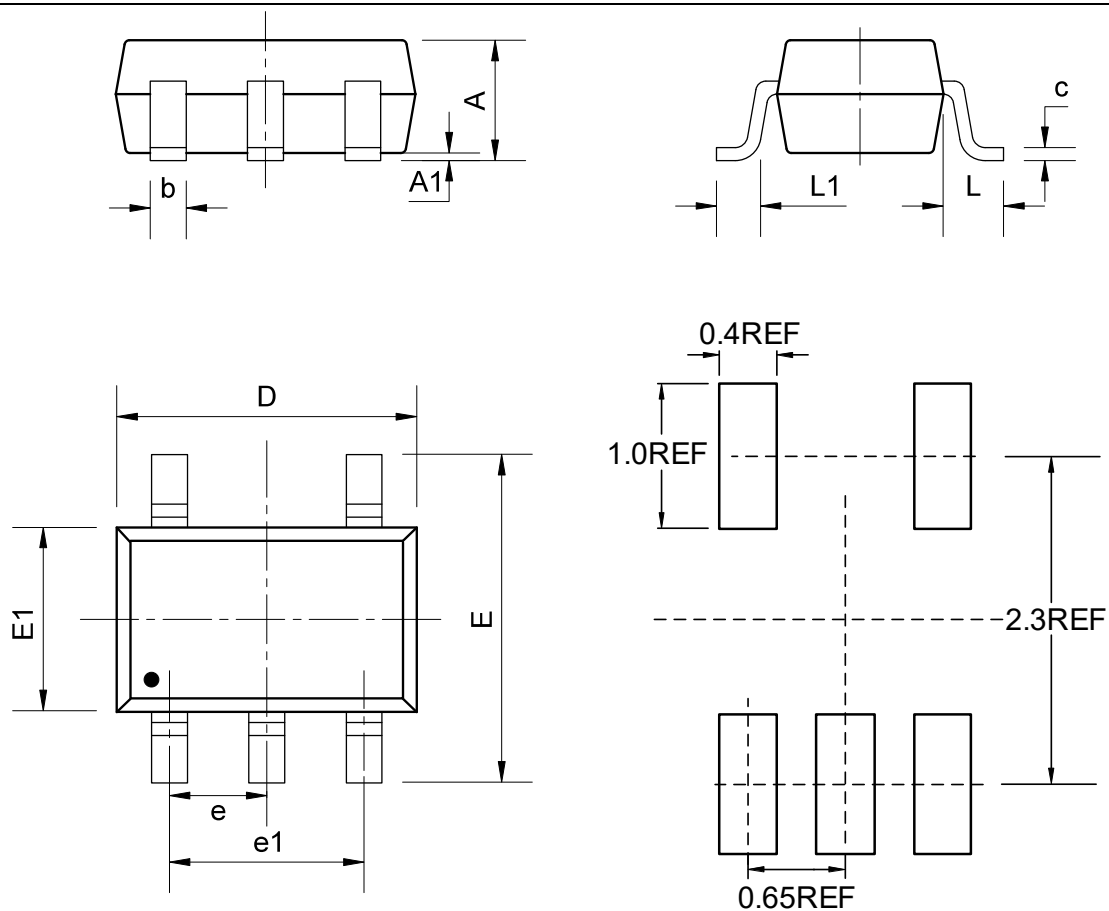
Table 1. Test Data

Supply Voltage	Input			Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	f_{max}	C_L	R_L	t_{PLH}, t_{PHL}
1.8V	V_{CC}	$\leq 3ns$	15MHz	15pF, 30pF	1M Ω	Open
2.5V	V_{CC}	$\leq 3ns$	25MHz	15pF, 30pF	1M Ω	Open
3.3V	3V	$\leq 3ns$	50MHz	15pF, 30pF	1M Ω	Open
5.0V	3V	$\leq 3ns$	50MHz	15pF, 30pF	1M Ω	Open

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Package Dimension

SC70-5 (1.3mm × 2.1mm)



COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	-	-	1.10
A1	0.00	-	0.15
b	0.15	-	0.35
c	0.08	-	0.20
D	2.00	2.10	2.30
e	0.65BSC		
e1	1.30BSC		
E	2.15	2.30	2.50
E1	1.15	1.30	1.45
L	0.50REF		
L1	0.33REF		

